



LED Display

Product Data Sheet

LTD-5260G-NBJ

Spec No.: DS30-2004-118

Effective Date: 05/26/2004

Revision: -

LITE-ON DCC

RELEASE

BNS-OD-FC001/A4

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FEATURES

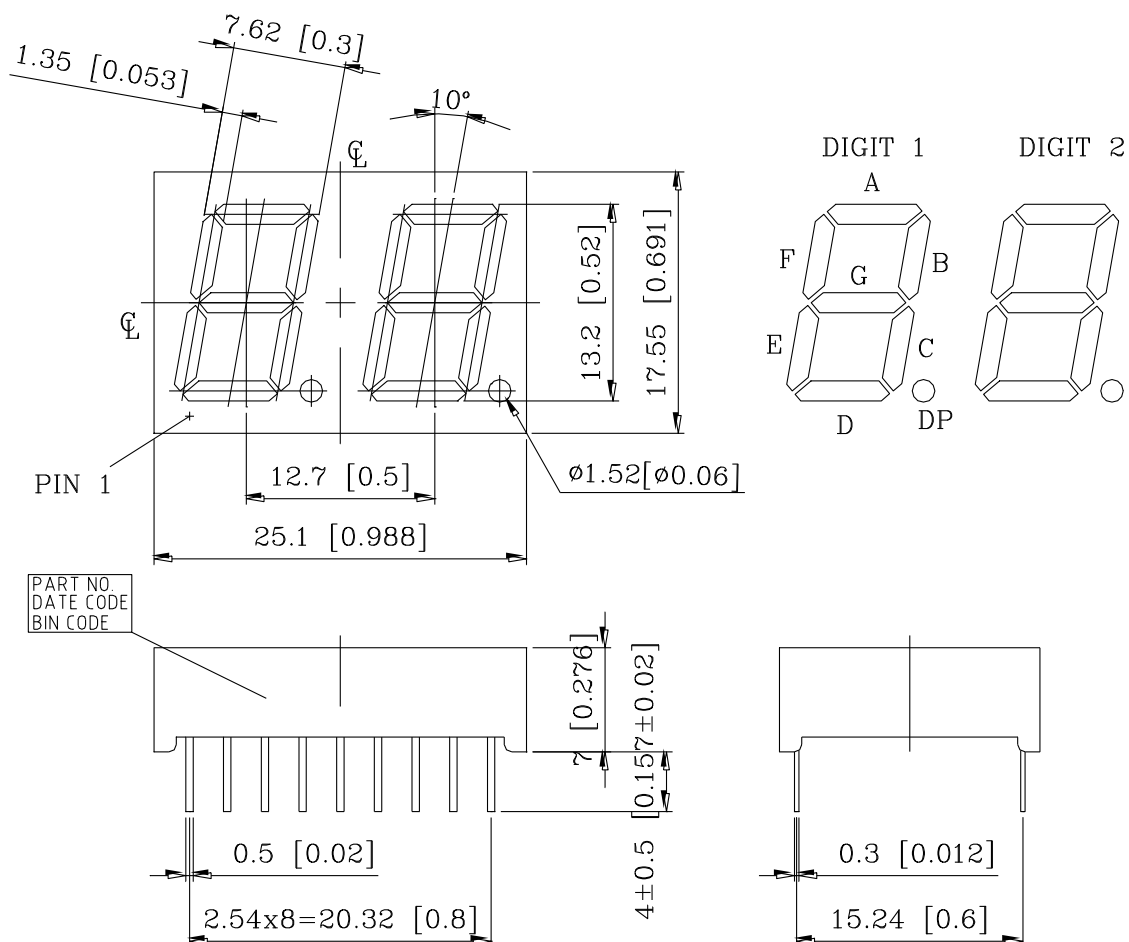
- * 0.52 inch (13.2mm) DIGIT HEIGHT
- * CONTINUOUS UNIFORM SEGMENTS
- * LOW POWER REQUIREMENT
- * EXCELLENT CHARACTERS APPEARANCE
- * HIGH BRIGHTNESS & HIGH CONTRAST
- * WIDE VIEWING ANGLE
- * SOLID STATE RELIABILITY
- * CATEGORIZED FOR LUMINOUS INTENSITY
- * **LEAD-FREE PACKAGE**

DESCRIPTION

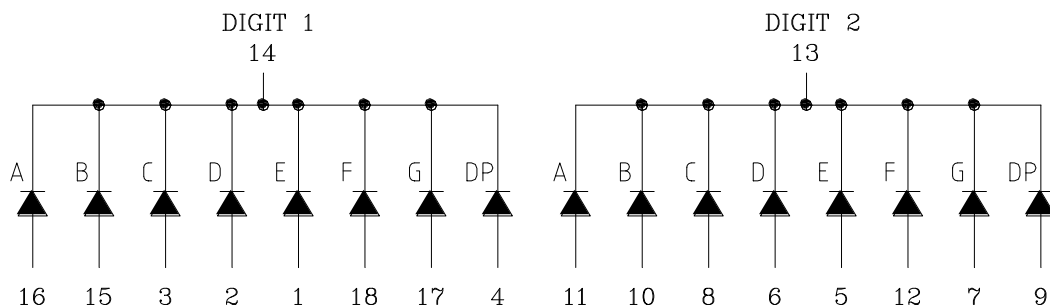
The LTD-5260G-NBJ is a 0.52inch (13.2mm) digit height dual digit seven-segment display. The device utilizes Green LED chips, which are made from GaP on a transparent GaP substrate, and has a black face and green segments.

DEVICE

PART NO.	DESCRIPTION
GREEN	COMMON CATHODE RT. HAND DECIMAL
LTD-5260G-NBJ	

PACKAGE DIMENSIONS


NOTES: All dimensions are in millimeters. Tolerances are ± 0.25 mm unless otherwise noted.

INTERNAL CIRCUIT DIAGRAM


PIN CONNECTION

No.	CONNECTION
1	ANODE E (DIGIT 1)
2	ANODE D (DIGIT 1)
3	ANODE C (DIGIT 1)
4	ANODE DP (DIGIT 1)
5	ANODE E (DIGIT 2)
6	ANODE D (DIGIT 2)
7	ANODE G (DIGIT 2)
8	ANODE C (DIGIT 2)
9	ANODE DP (DIGIT 2)
10	ANODE B (DIGIT 2)
11	ANODE A (DIGIT 2)
12	ANODE F (DIGIT 2)
13	COMMON CATHODE (DIGIT 2)
14	COMMON CATHODE (DIGIT 1)
15	ANODE B (DIGIT 1)
16	ANODE A (DIGIT 1)
17	ANODE G (DIGIT 1)
18	ANODE F (DIGIT 1)

ABSOLUTE MAXIMUM RATING

PARAMETER	MAXIMUM RATING	UNIT
Power Dissipation Per Chip	75	mW
Peak Forward Current Per Chip (1/10 Duty Cycle, 0.1ms Pulse Width)	100	mA
Continuous Forward Current Per Chip	25	mA
Derating Linear From 25°C Per Chip	0.33	mA/°C
Reverse Voltage Per Chip	5	V
Operating Temperature Range	-35°C to +85°C	
Storage Temperature Range	-35°C to +85°C	
Solder Temperature: max 260°C for max 3sec at 1.6mm below seating plane		

TRICAL / OPTICAL CHARACTERISTICS AT T_A=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I _V	800	2200		μcd	I _F =10mA
Peak Emission Wavelength	λ _p		565		nm	I _F =20mA
Spectral Line Half-Width	Δλ		30		nm	I _F =20mA
Dominant Wavelength	λ _d		569		nm	I _F =20mA
Forward Voltage Per Chip	V _F		2.1	2.6	V	I _F =20mA
Reverse Current Per Chip	I _R			100	μA	V _R =5V
Luminous Intensity Matching Ratio	I _V -m			2:1		I _F =10mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

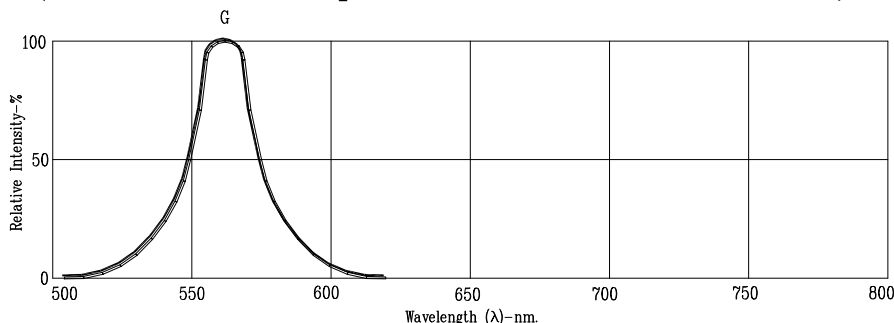


Fig1. RELATIVE INTENSITY VS. WAVELENGTH

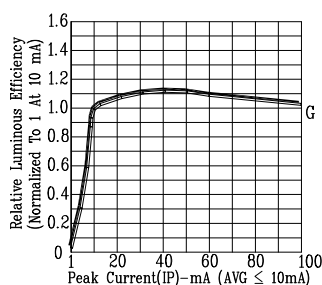


Fig2. RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT (REFRESH RATE 1KHz)

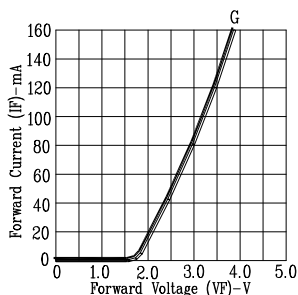


Fig3. FORWARD CURRENT VS. FORWARD VOLTAGE

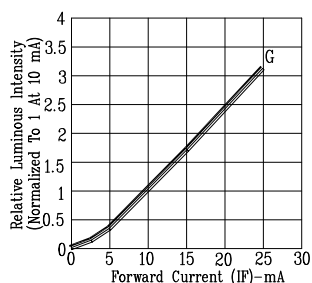


Fig4. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

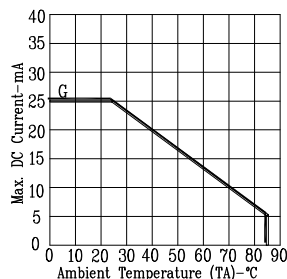


Fig5. MAX. ALLOWABLE DC CURRENT VS. AMBIENT TEMPERATURE.

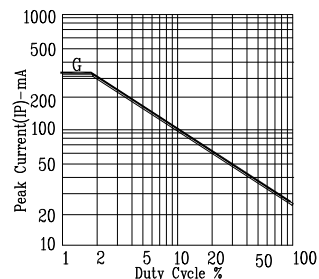


Fig6. MAX. PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE 1KHz)

NOTE: G=GREEN